

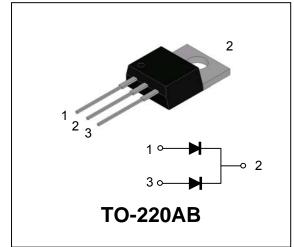
# MBR3040CT to MBR30200CT

## Schottky Barrier Rectifiers

## Main product characteristics

I <sub>F(AV)</sub>	30A (2 x 15A)			
$V_{RRM}$	40V to 200V			
$T_{j(MAX)}$	175°C			





#### Features and benefits

- Plastic package with UL 94V-0 flammability classification
- Flame retardant epoxy molding component
- Guardring for overvoltage protection
- · Low power loss, high efficiency
- RoHS compliant (2002/95/EC)

## **Description and applications**

Double Schottky configuration for use in low voltage, high frequency inverters, free wheeling and polarity protection applications. The Metal silicon junction means the devices are majority carrier conduction leading to low power loss and high efficiency.

# Electrical characteristics<sup>(1)</sup>

Symbol	Parameter	MBR3040CT	MBR3045CT	MBR3050CT	MBR3060CT	MBR3080CT	MBR3090CT	MBR30100CT	MBR30150CT	MBR30200CT	Unit
$V_{RRM}$	Max Peak Repetitive Reverse Voltage		45	50	60	80	90	100	150	200	V
$V_{R(RMS)}$	Max RMS Reverse Voltage		31.5	35	42	56	63	70	105	140	٧
$V_R$	Max DC Blocking Voltage		45	50	60	80	90	100	150	200	٧
I <sub>F(AV)</sub>	Max average forward current (see fig.1)		30					Α			
I <sub>FSM</sub>	Non repetitive peak forward surge current (8.3ms single half sine wave)		275					Α			
$V_{F}$	Max forward voltage @ 15A (per leg)		.70	0.75 0.80			0	.90	V		
I <sub>R</sub> <sup>(2)</sup>	Maximum instantaneous T <sub>J</sub> = 25°C	0.05							m A		
IR` ′	reverse current at rated V <sub>R</sub> T <sub>J</sub> = 125°C							mA			
T <sub>STG</sub> , T <sub>J</sub>	Storage and Junction temperature	-55 to +150	-65 to +175						°C		

<sup>(1)</sup> All ratings at 25°C unless specified otherwise

<sup>(2)</sup> Measured with a test pulse of 380µs to minimize self-heating effect



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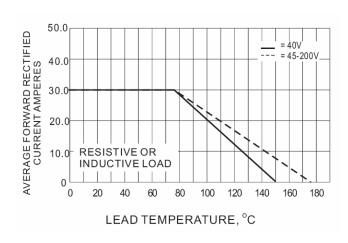


Fig.1 Forward current derating curve. For capacitive load derate by 20%

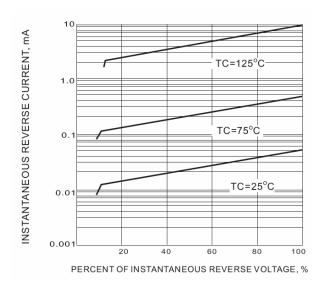


Fig.3 Typical reverse characteristics

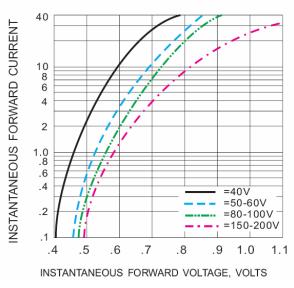


Fig.2 Typical instantaneous forward characteristics

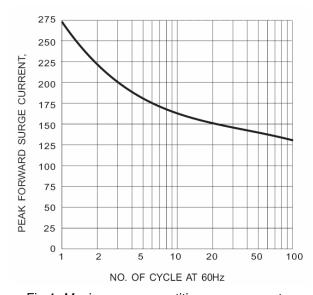


Fig.4 Maximum non repetitive surge current

#### **Thermal Characteristics**

Symbol	Parameter	Value	Unit	
$R_{\Theta JC}$	Junction to case	1.4	°C/W	

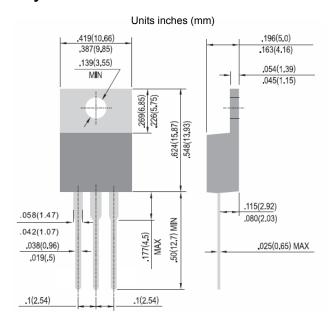


# **MBR3040CT to MBR30200CT**

Schottky Barrier Rectifiers

### **Mechanical Characteristics**

#### **Physical dimensions**



# **Ordering information**

Product order code	Marking	Package	Weight	Base qty	Delivery mode
MBR30xxxCTe3/TU	MSC yyww MBR30xxxCT →   ←	TO-220AB	1.895 g	2000	Tube

Commercial Business Unit Microsemi Corporation

Microsemi Commercial Offshore de Macau Limitada Avenida Doutor Mario Soares Bank of China Building, 18/F, Unit D Macau SAR

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